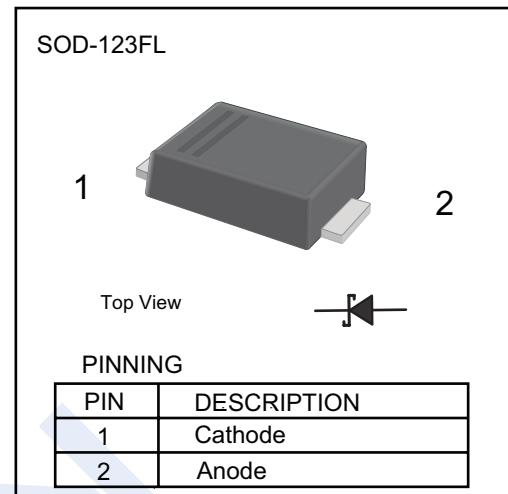


Schottky Diodes

SS32FL ~ SS320FL

■ Features

- Metal silicon junction, majority carrier conduction
- For surface mounted applications
- Low power loss, high efficiency
- High forward surge current capability
- For use in low voltage, high frequency inverters, free wheeling, and polarity protection applications



■ Absolute Maximum Ratings Ta = 25°C unless otherwise specified

Parameter	Symbol	SS 32FL	SS 34FL	SS 36FL	SS 38FL	SS 310FL	SS 312FL	SS 315FL	SS 320FL	Unit			
Repetitive Peak Reverse Voltage	V _{RRM}	20	40	60	80	100	120	150	200	V			
Surge Peak Reverse Voltage	V _{RSM}	14	28	42	56	70	84	105	140				
Maximum DC Blocking Voltage	V _{DC}	20	40	60	80	100	120	150	200				
Averaged Forward Current	I _O	3				70				A			
Peak forward surge current	I _{FSM}	80			70								
Instantaneous Forward Voltage at 3A	V _F	0.55		0.7		0.85		0.95		V			
Maximum DC Reverse Current T _A =25°C at rated DC blocking voltage T _A =100°C	I _R	0.5		0.3				5					
Typical Junction Capacitance *1	C _J	250		160				pF					
Typical thermal resistance *2	R _{thJA}	80				°C/W							
Junction Temperature	T _j	150				°C							
Storage Temperature	T _{stg}	-55 to 150											

* 1 Measured at 1MHz and applied reverse voltage of 4V D.C

* 2 P.C.B. mounted with 2" × 2" (5×5 cm) copper pad areas.

■ Marking

NO.	SS32FL	SS34FL	SS36FL	SS38FL	SS310FL	SS312FL	SS315FL	SS320FL
Marking	S32	S34	S36	S38	S310	S312	S315	S320

Schottky Diodes

SS32FL ~ SS320FL

■ Typical Characteristics

Fig.1 Forward Current Derating Curve

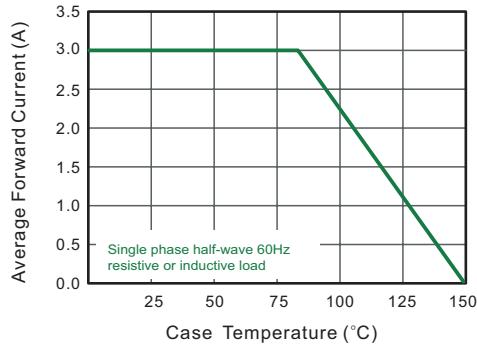


Fig.2 Typical Reverse Characteristics

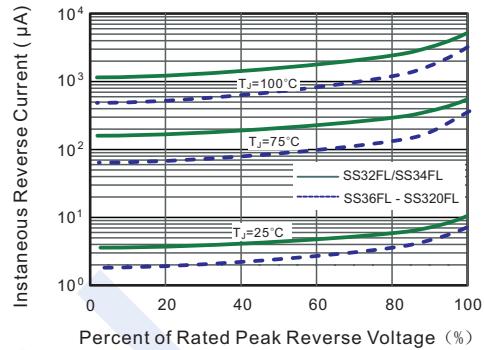


Fig.3 Typical Forward Characteristic

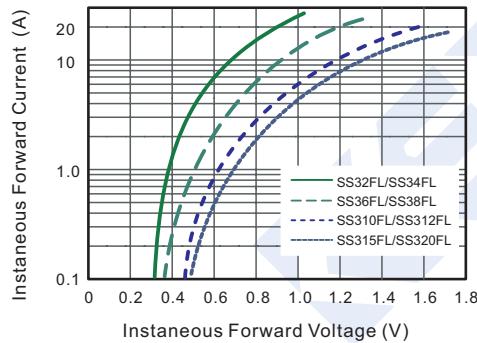


Fig.4 Typical Junction Capacitance

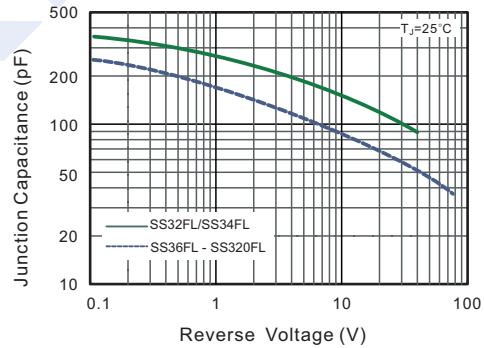


Fig.5 Maximum Non-Repetitive Peak Forward Surge Current

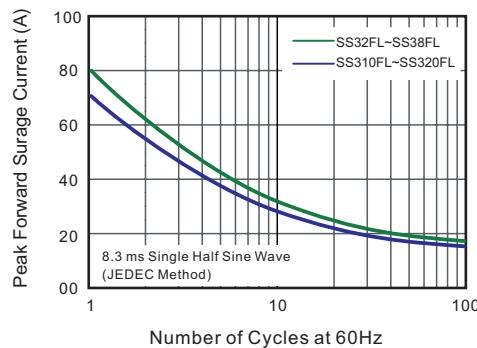
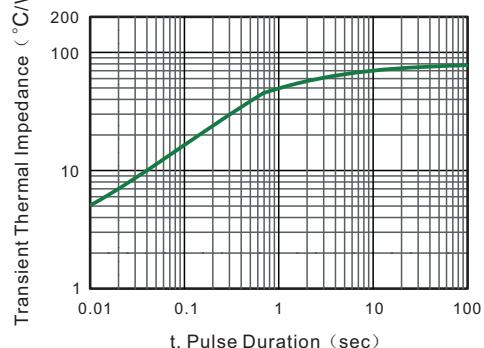


Fig.6- Typical Transient Thermal Impedance



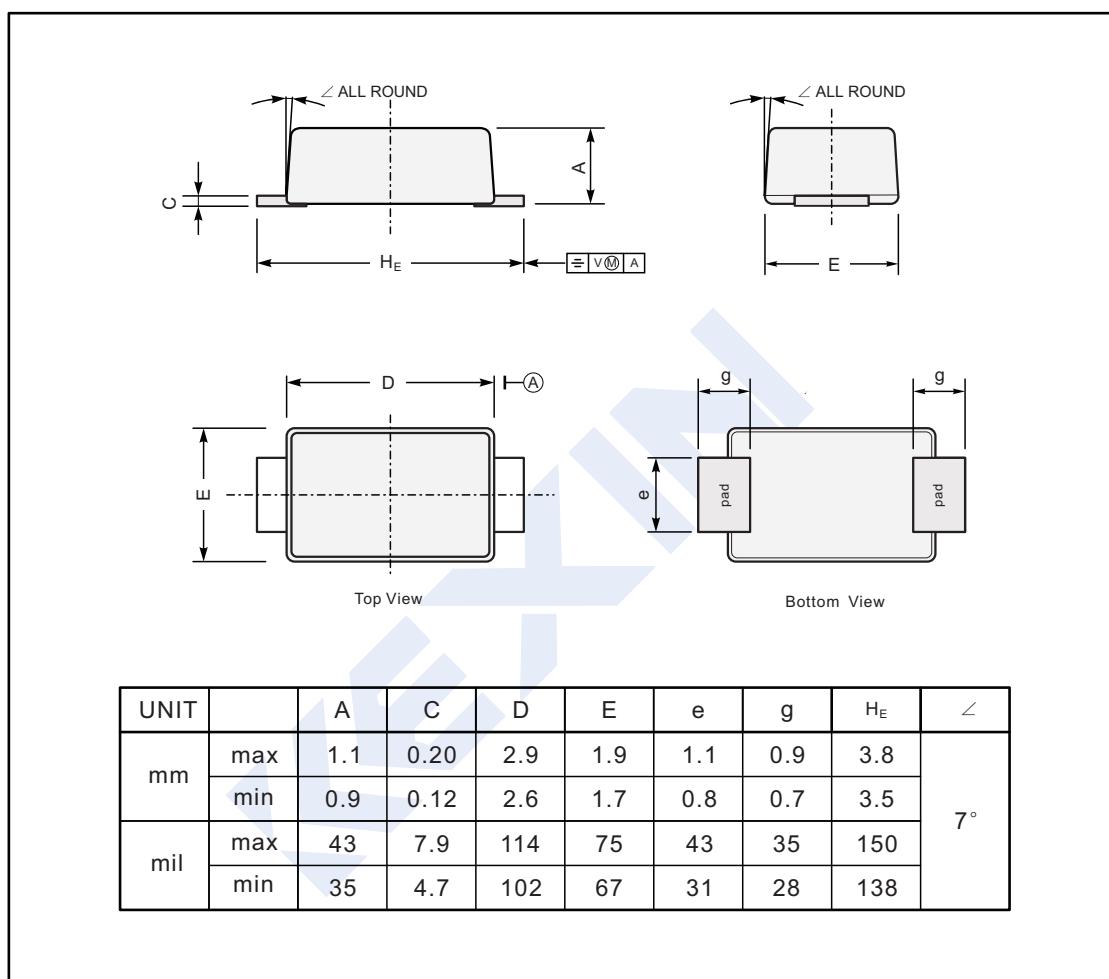
Schottky Diodes

SS32FL ~ SS320FL

■ Package Outline Dimensions

Plastic surface mounted package; 2 leads

SOD-123FL



■ The Recommended Mounting Pad Size

